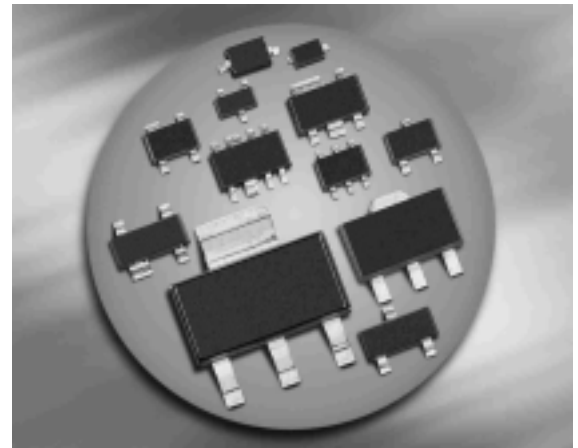
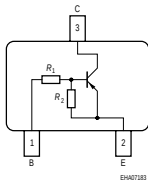


PNP Silicon Digital Transistor

- Switching circuit, inverter, interface circuit, driver circuit
- Built in resistor ($R_1=2.2k\Omega$, $R_2=2.2k\Omega$)
- BCR153U: Two internally isolated transistors with good matching in one multichip package



BCR153F/L3 BCR153T



Type	Marking	Pin Configuration						Package
BCR153F	WBs	1=B	2=E	3=C	-	-	-	TSFP-3
BCR153L3	WB	1=B	2=E	3=C	-	-	-	TSFP-3-4
BCR153T	WB	1=B	2=E	3=C	-	-	-	SC75

Maximum Ratings

Parameter	Symbol	Value	Unit
Collector-emitter voltage	V_{CEO}	50	V
Collector-base voltage	V_{CBO}	50	
Input forward voltage	$V_{i(fwd)}$	20	
Input reverse voltage	$V_{i(rev)}$	10	
Collector current	I_C	100	mA
Total power dissipation	P_{tot}		mW
BCR153F, $T_S \leq 128^\circ\text{C}$		250	
BCR153L3, $T_S \leq 135^\circ\text{C}$		250	
BCR153T, $T_S \leq 109^\circ\text{C}$		250	
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-65 ... 150	

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point ¹⁾	R_{thJS}		K/W
BCR153F		≤ 90	
BCR153L3		≤ 60	
BCR153T		≤ 165	

Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	

DC Characteristics

Collector-emitter breakdown voltage $I_C = 100 \mu\text{A}$, $I_B = 0$	$V_{(BR)CEO}$	50	-	-	V
Collector-base breakdown voltage $I_C = 10 \mu\text{A}$, $I_E = 0$	$V_{(BR)CBO}$	50	-	-	
Collector-base cutoff current $V_{CB} = 40 \text{ V}$, $I_E = 0$	I_{CBO}	-	-	100	nA
Emitter-base cutoff current $V_{EB} = 10 \text{ V}$, $I_C = 0$	I_{EBO}	-	-	3.5	mA
DC current gain ²⁾ $I_C = 20 \text{ mA}$, $V_{CE} = 5 \text{ V}$	h_{FE}	20	-	-	-
Collector-emitter saturation voltage ²⁾ $I_C = 20 \text{ mA}$, $I_B = 1 \text{ mA}$	V_{CEsat}	-	-	0.3	V
Input off voltage $I_C = 100 \mu\text{A}$, $V_{CE} = 5 \text{ V}$	$V_{i(off)}$	0.8	-	1.5	
Input on voltage $I_C = 2 \text{ mA}$, $V_{CE} = 0.3 \text{ V}$	$V_{i(on)}$	0.8	-	2.5	
Input resistor	R_1	1.5	2.2	2.9	kΩ
Resistor ratio	R_1/R_2	0.9	1	1.1	-

AC Characteristics

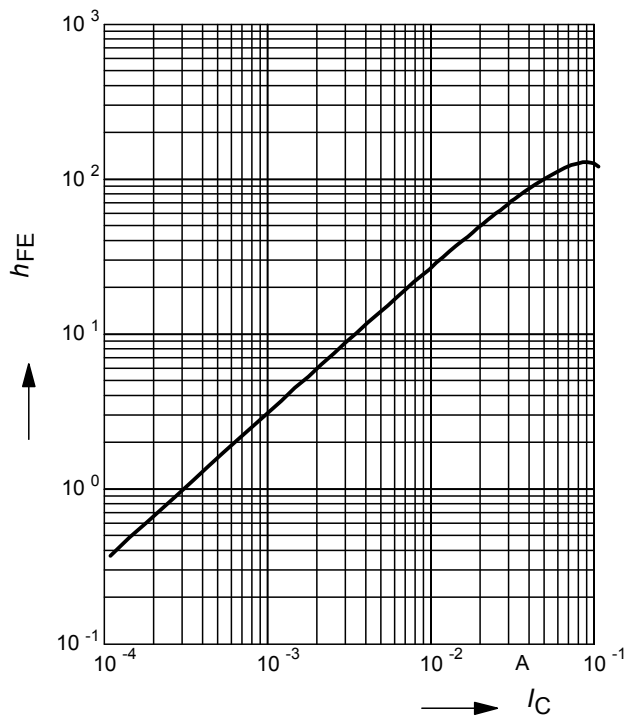
Transition frequency $I_C = 10 \text{ mA}$, $V_{CE} = 5 \text{ V}$, $f = 100 \text{ MHz}$	f_T	-	200	-	MHz
Collector-base capacitance $V_{CB} = 10 \text{ V}$, $f = 1 \text{ MHz}$	C_{cb}	-	3	-	pF

¹⁾For calculation of R_{thJA} please refer to Application Note Thermal Resistance

²⁾Pulse test: $t < 300 \mu\text{s}$; $D < 2\%$

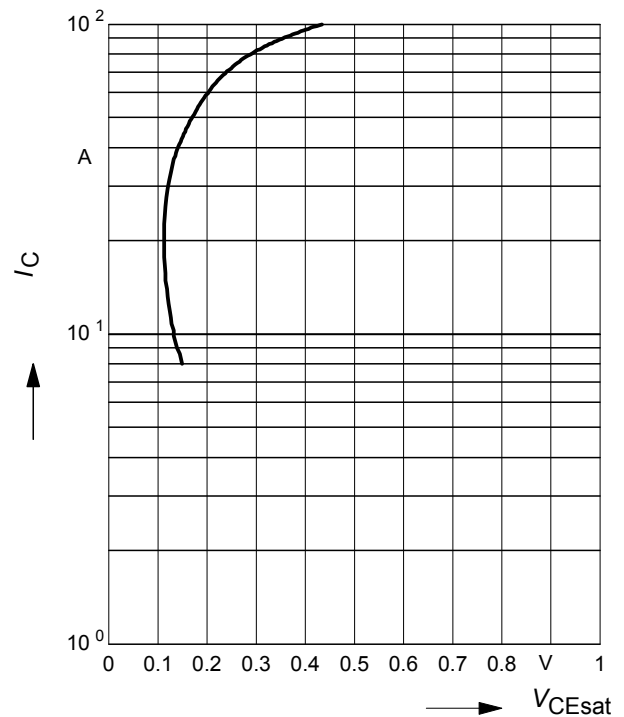
DC current gain $h_{FE} = f(I_C)$

$V_{CE} = 5V$ (common emitter configuration)



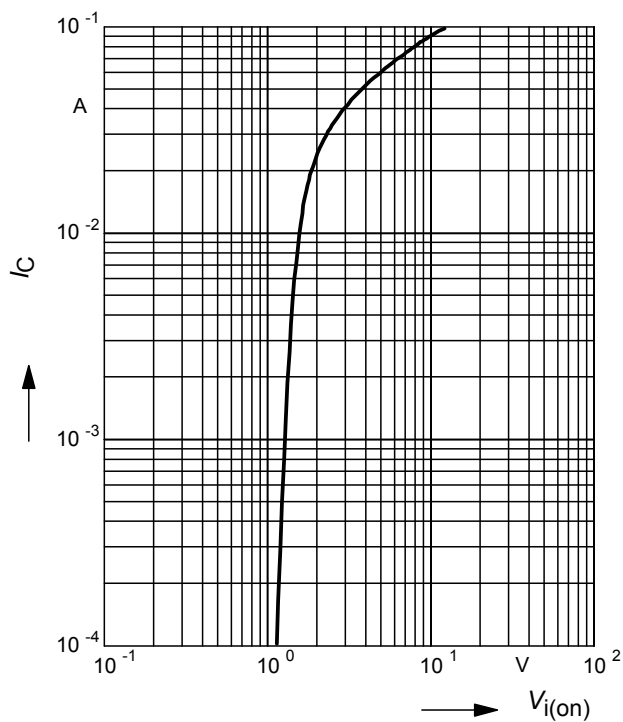
Collector-emitter saturation voltage

$V_{CEsat} = f(I_C), h_{FE} = 20$



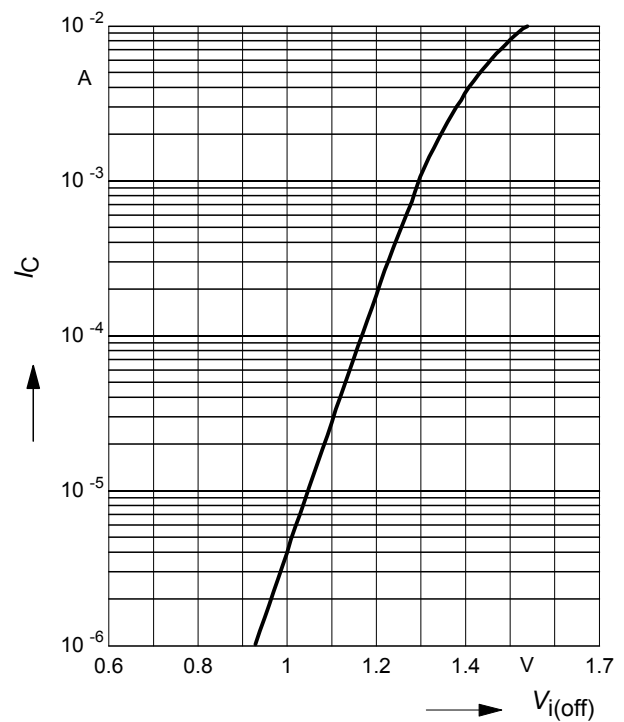
Input on Voltage $V_{i(on)} = f(I_C)$

$V_{CE} = 0.3V$ (common emitter configuration)



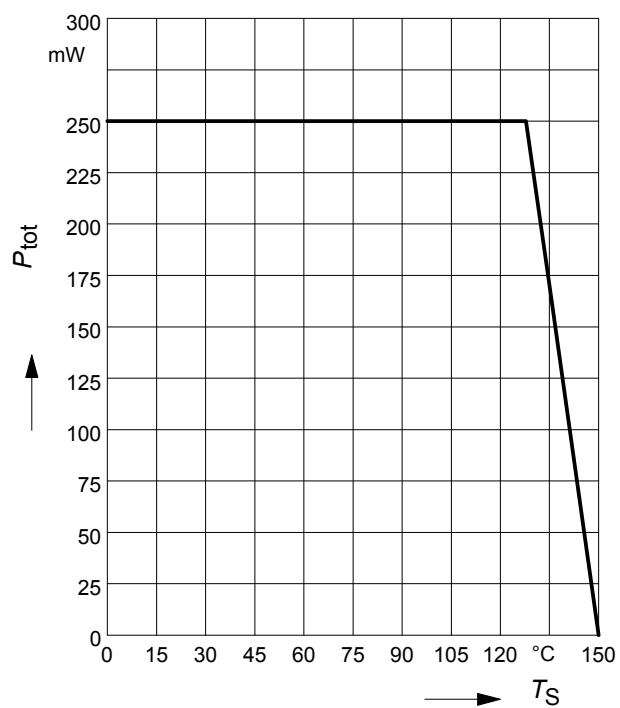
Input off voltage $V_{i(off)} = f(I_C)$

$V_{CE} = 5V$ (common emitter configuration)



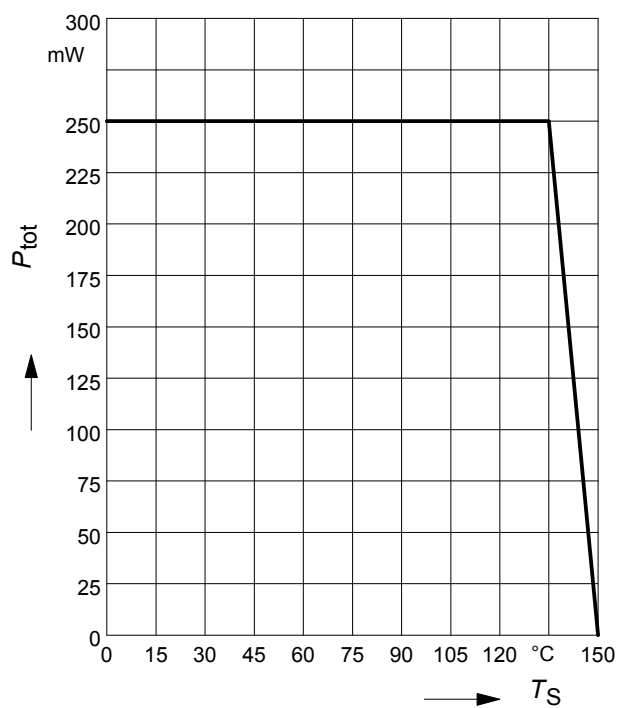
Total power dissipation $P_{\text{tot}} = f(T_S)$

BCR153F



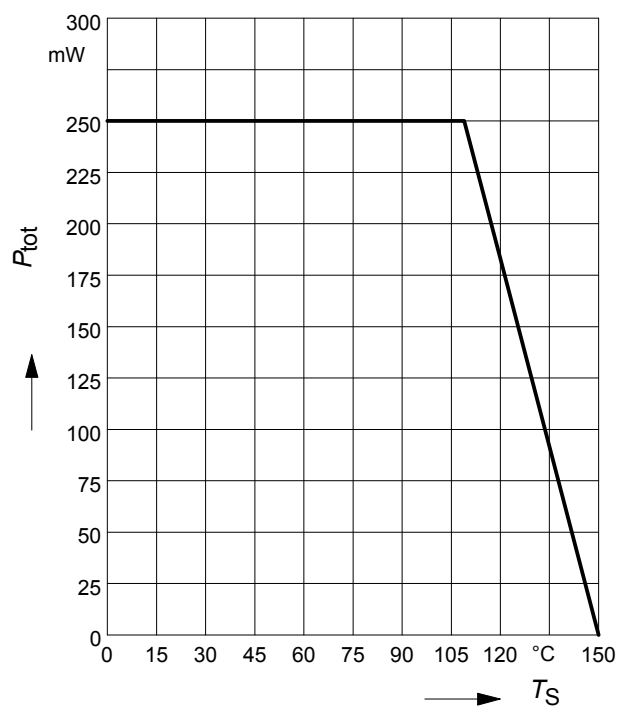
Total power dissipation $P_{\text{tot}} = f(T_S)$

BCR153L3



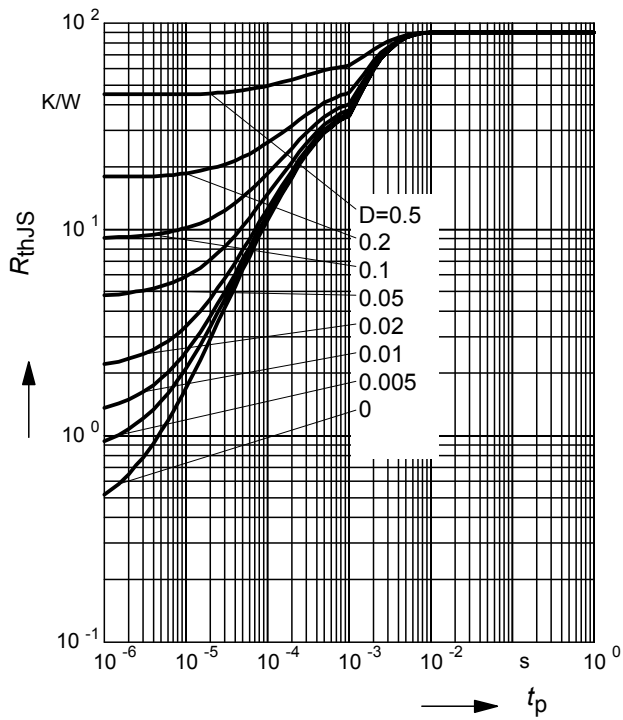
Total power dissipation $P_{\text{tot}} = f(T_S)$

BCR153T



Permissible Puls Load $R_{thJS} = f(t_p)$

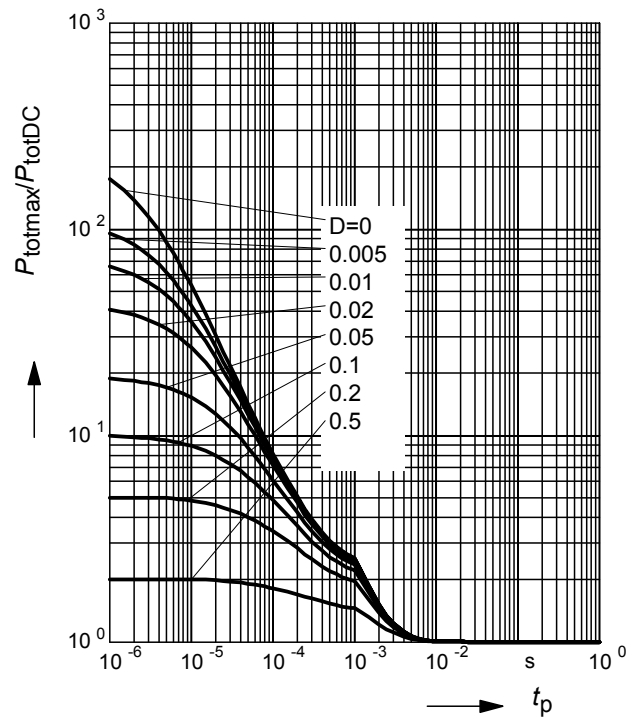
BCR153F



Permissible Pulse Load

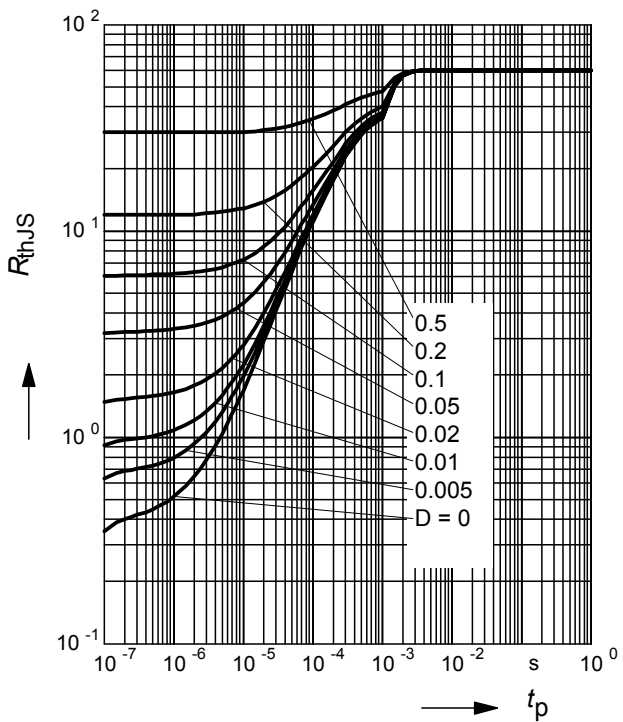
$$P_{totmax}/P_{totDC} = f(t_p)$$

BCR153F



Permissible Puls Load $R_{thJS} = f(t_p)$

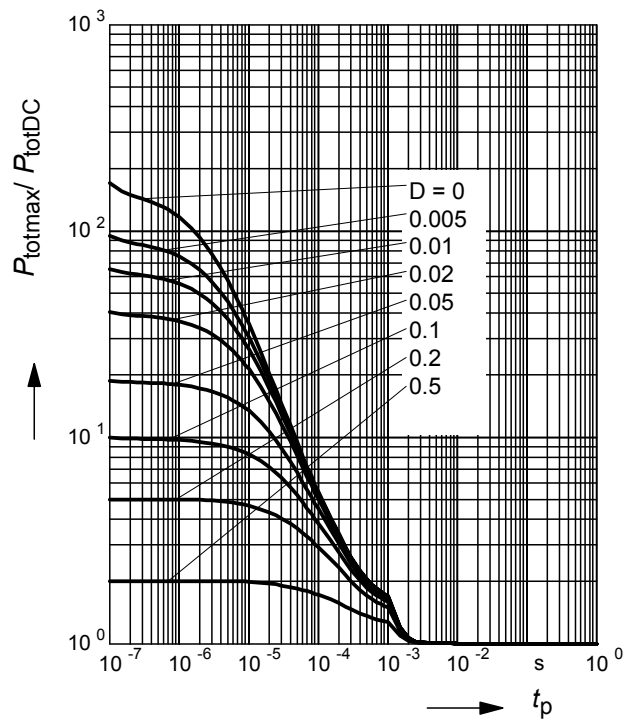
BCR153L3



Permissible Pulse Load

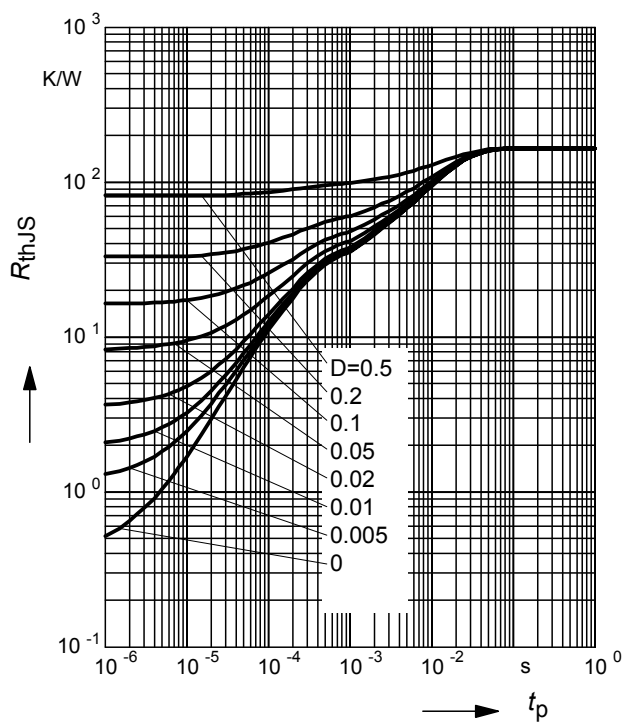
$$P_{totmax}/P_{totDC} = f(t_p)$$

BCR153L3



Permissible Puls Load $R_{thJS} = f(t_p)$

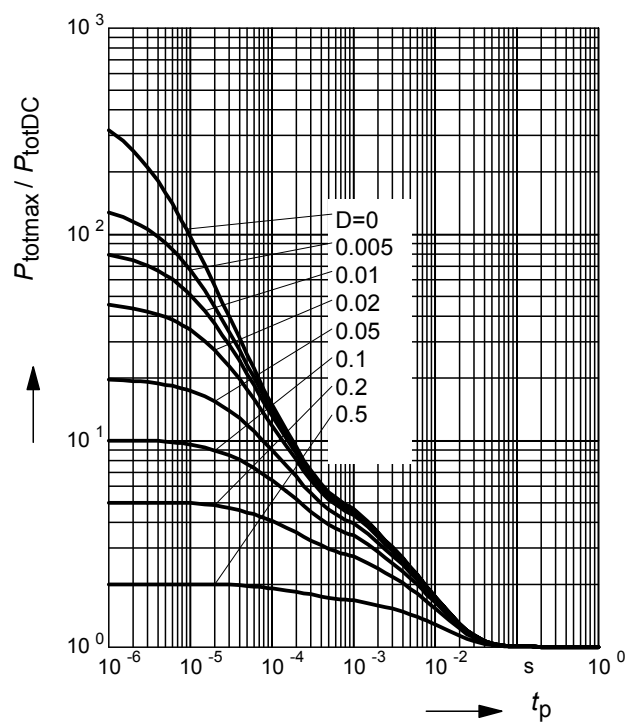
BCR153T



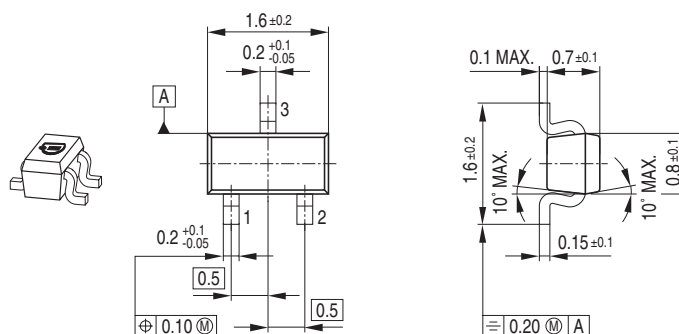
Permissible Pulse Load

$$P_{totmax}/P_{totDC} = f(t_p)$$

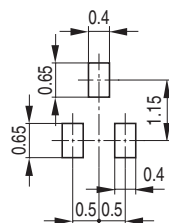
BCR153T



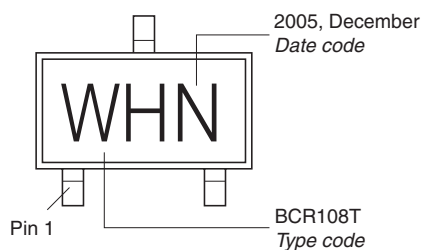
Package Outline



Foot Print

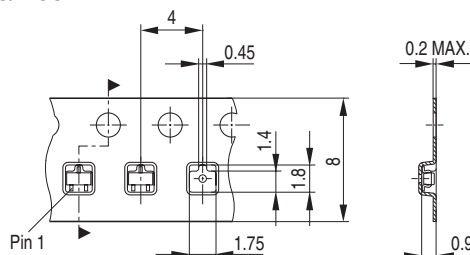


Marking Layout (Example)



Standard Packing

Reel $\varnothing 180 \text{ mm}$ = 3.000 Pieces/Reel
 Reel $\varnothing 330 \text{ mm}$ = 10.000 Pieces/Reel



Date Code marking for discrete packages with one digit (SCD80, SC79, SC75¹⁾) CES-Code

Month	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014
01	a	p	A	P	a	p	A	P	a	p	A	P
02	b	q	B	Q	b	q	B	Q	b	q	B	Q
03	c	r	C	R	c	r	C	R	c	r	C	R
04	d	s	D	S	d	s	D	S	d	s	D	S
05	e	t	E	T	e	t	E	T	e	t	E	T
06	f	u	F	U	f	u	F	U	f	u	F	U
07	g	v	G	V	g	v	G	V	g	v	G	V
08	h	x	H	X	h	x	H	X	h	x	H	X
09	j	y	J	Y	j	y	J	Y	j	y	J	Y
10	k	z	K	Z	k	z	K	Z	k	z	K	Z
11	l	2	L	4	l	2	L	4	l	2	L	4
12	n	3	N	5	n	3	N	5	n	3	N	5

1) New Marking Layout for SC75, implemented at October 2005.

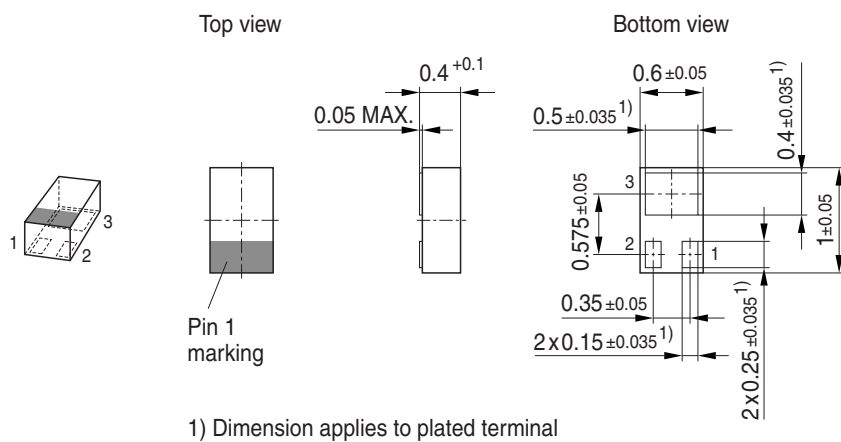
The technical drawing shows two views of the MPM-0600 sensor:

- Front View (Left):** Shows a rectangular component with three pins labeled 1, 2, and 3. Dimensions include a total width of 1.2 ± 0.05 , a pin pitch of 0.2 ± 0.05 , and individual pin widths of 0.2 ± 0.05 . Pin 1 has a height of 0.4 ± 0.05 , while pins 2 and 3 have heights of 0.4 ± 0.05 .
- Side View (Right):** Shows the profile of the sensor. It features a top flange with a thickness of 0.8 ± 0.05 and a mounting hole with a diameter of 0.55 ± 0.04 . The main body has a height of 1.2 ± 0.05 and a base width of 0.15 ± 0.05 . A chamfer angle of 10° MAX. is indicated.

Technical drawing of a mechanical part with dimensions: 0.4, 0.45, 1.05, 0.4, 0.4.

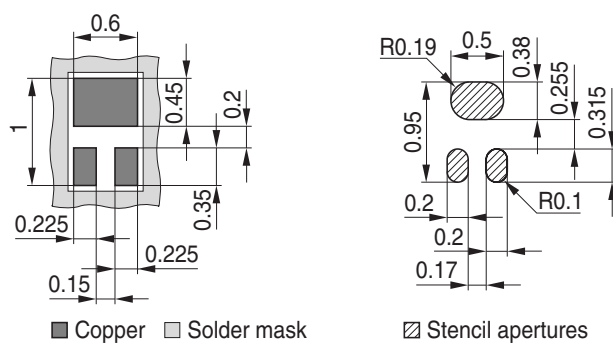
Technical drawing of a mechanical part showing a top view and a side view. The top view includes dimensions: 4, 0.3, 1.2, 1.5, 8, 1.35, and Pin 1. The side view includes dimensions: 0.2 and 0.7.

Package Outline

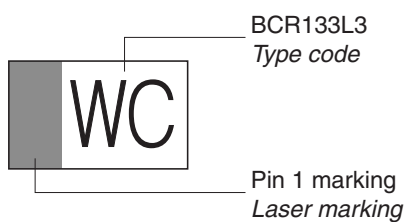


Foot Print

For board assembly information please refer to Infineon website "Packages"

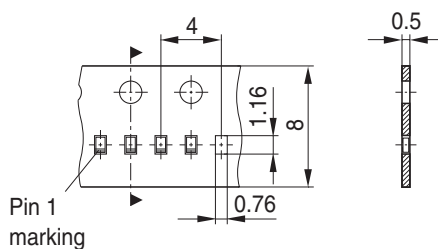


Marking Layout



Standard Packing

Reel ø180 mm = 15.000 Pieces/Reel



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